

## SOT223 PNP SILICON PLANAR HIGH VOLTAGE TRANSISTOR

## **FEATURES**

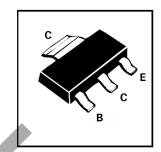
- \* High breakdown voltage
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

## **APPLICATIONS**

 Suitable for video output stages in TV sets and switch mode power supplies COMPLIMENTARY TYPE – PARTMARKING DETAIL –

FZTA42 DEVICE TYPE IN FULL



## ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	-300	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-300	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Base Current	I <sub>B</sub>	-100	mA
Continuous Collector Current	Ic	-500	mA
Power Dissipation at T <sub>amb</sub> =25°C	P <sub>tot</sub>	2	W
Operating and Storage Temperature Range	T <sub>j</sub> :T <sub>stg</sub>	-55 to +150	°C

# ELECTRICAL CHARACTERISTICS (at Tamb = 25°C).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-300			V	I <sub>C</sub> =-100μA, I <sub>E</sub> =0
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	-300			V	I <sub>C</sub> =-1mA, I <sub>B</sub> =0*
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-5			V	I <sub>E</sub> =-100μA, I <sub>C</sub> =0
Collector Cut-Off Current	I <sub>CBO</sub>			-0.25	μА	$V_{CB}$ =-200V, $I_{E}$ =0
Emitter Cut-Off Current	I <sub>EBO</sub>			-0.1	μΑ	V <sub>EB</sub> =-3V, I <sub>C</sub> =0
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>			-0.5	V	I <sub>C</sub> =-20mA, I <sub>B</sub> =-2mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>			-0.9	V	I <sub>C</sub> =-20mA, I <sub>B</sub> =-2mA
Static Forward Current Transfer Ratio	h <sub>FE</sub>	25 40 25				I <sub>C</sub> =-1mA, V <sub>CE</sub> =-10V* I <sub>C</sub> =-10mA, V <sub>CE</sub> =-10V* I <sub>C</sub> =-30mA, V <sub>CE</sub> =-10V*
Transition Frequency	f <sub>T</sub>	50			MHz	I <sub>C</sub> =-10mA, V <sub>CE</sub> =-20V f=20MHz
Output Capacitance	C <sub>obo</sub>			6	pF	V <sub>CB</sub> =-20V, f=1MHz

<sup>\*</sup> Measured under pulsed conditions. Pulse width=300 $\mu$ s. Duty cycle  $\leq$  2% For typical characteristics graphs see FMMTA92 datasheet.



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